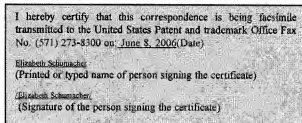


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Wen Lin, et al.
Serial No.: 10/814,682
Filed: March 31, 2004
Title: **SEMICONDUCTOR DEVICE HAVING A DOPED LATTICE
MATCHING LAYER AND A METHOD OF MANUFACTURE
THEREFOR**
Grp./A.U.: 2823
Examiner: Julio J. Maldonado

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450



Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed March 21, 2006, please amend the above-identified application as follows: